

SURFACE MOUNT SILICON SCHOTTKY DIODES





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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMSSH-3 Series types are Silicon Schottky Diodes, epoxy molded in a SUPERmini[™] surface mount package, designed for fast switching applications requiring a low forward voltage drop.

CMSSH-3A: DUAL, COMMON ANODE M CMSSH-3C: DUAL, COMMON CATHODE M	MARKING CODE: 95D MARKING CODE: B1D MARKING CODE: B2D MARKING CODE: A5D
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MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
Peak Repetitive Reverse Voltage	V _{RRM}	30	V
Continuous Forward Current	١ _F	100	mA
Peak Repetitive Forward Current	IFRM	200	mA
Peak Forward Surge Current, tp=10ms	IFSM	750	mA
Power Dissipation	PD	275	mW
Operating and Storage Junction Temperature	т _Ј , т _{stg}	-65 to +150	°C
Thermal Resistance	Θ _{JA}	455	°C/W

ELECTRICAL CHARACTERISTICS PER DIODE: (T_A=25°C unless otherwise noted)

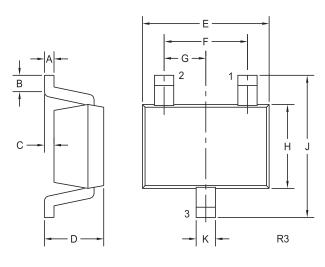
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SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
IR	V _R =25V		90	500	nA
I _R	V _R =25V, T _A =100°C		25	100	μA
BVR	I _R =100μA	30			V
VF	I _F =2.0mA		0.29	0.33	V
V _F	I _F =15mA		0.40	0.45	V
VF	I _F =100mA		0.74	1.00	V
С _Т	V _R =1.0V, f=1.0MHz		7.0		pF
t _{rr}	$I_F = I_R = 10$ mA, $I_{rr} = 1.0$ mA, $R_L = 100\Omega$			5.0	ns

R3 (9-February 2010)



CMSSH-3 CMSSH-3A CMSSH-3C CMSSH-3S

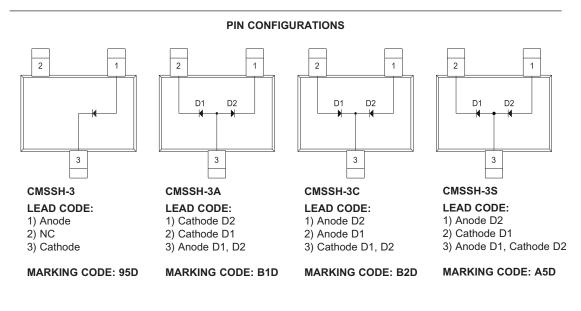
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SOT-323 CASE - MECHANICAL OUTLINE

DIMENSIONS					
	INCHES		MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MAX	
А	0.002	0.008	0.05	0.20	
В	0.004	-	0.10	-	
С	-	0.004	-	0.10	
D	0.031	0.043	0.80	1.10	
E	0.071	0.087	1.80	2.20	
F	0.051		1.30		
G	0.026		0.	65	
Н	0.045	0.053	1.15	1.35	
J	0.079	0.087	2.00	2.20	
K	0.008	0.016	0.20	0.40	
SOT-323 (REV/· R3)					

SOT-323 (REV: R3)



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